



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

May 20, 2026

IGI Report Number

LG794625855

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

ROUND BRILLIANT

Measurements

8.20 - 8.23 X 4.91 MM

GRADING RESULTS

Carat Weight

2.00 CARATS

Color Grade

E

Clarity Grade

VVS 1

Cut Grade

IDEAL

ADDITIONAL GRADING INFORMATION

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

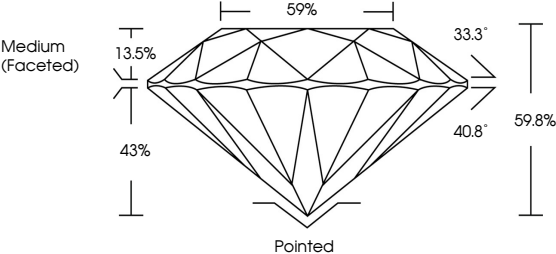
NONE

Inscription(s)

 LG794625855

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

PROPORTIONS



Medium (Faceted)

59%

33.3°

40.8°

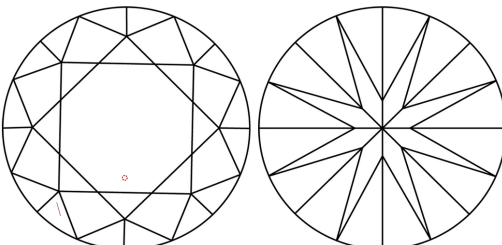
59.8%

43%

13.5%

Pointed

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VVS 1-2 VS 1-2 SI 1-2 I 1-3

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included



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